

	Type	Hits	Search Text	DBs	Time Stamp
1	IS&R	4214	(257/637,639,640,642,643,751,758,759,760,762,773).CCLS.	US-PGPUB; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	2007/02/20 16:03
2	BRS	217	S49 and ((carbon near3 silicon adj (oxide dioxide di-oxide)) SiOC C-SiO)	US-PGPUB; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	2007/02/20 16:08
3	IS&R	5233	(438/622,623,624,687,769,780,791).CCLS.	US-PGPUB; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	2007/02/20 16:06
4	IS&R	4871	(438/622,623,624,687,769,780,791).CCLS.	USPAT	2007/02/20 16:06
5	IS&R	6249	(257/637,639,640,642,643,751,758,759,760,762,773).CCLS.	USPAT	2007/02/20 15:44
6	BRS	237	S48 and ((carbon near3 silicon adj (oxide dioxide di-oxide)) SiOC C-SiO)	USPAT	2007/02/20 16:07
7	BRS	1176	(silicon adj carbide SiC Si-C) with (organic and inorganic)	USPAT	2007/02/22 18:55
8	BRS	340	(silicon adj carbide SiC Si-C) with (organic and inorganic) and semiconductor	USPAT	2007/02/22 19:09
9	BRS	18	((((carbon near3 silicon adj (oxide dioxide di-oxide oxycarbide oxy-carbide)) SiOC C-SiO) and content).clm.	US-PGPUB	2007/02/28 21:08
10	BRS	32	((carbon near3 silicon adj (oxide dioxide di-oxide oxycarbide oxy-carbide)) SiOC C-SiO) with ("%")	USPAT	2007/02/28 21:00
11	BRS	70	((carbon near3 silicon adj (oxide dioxide di-oxide oxycarbide oxy-carbide)) SiOC C-SiO) with ("%")	US-PGPUB; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	2007/02/28 21:00